TOSHIBA Photocoupler Photo Relay

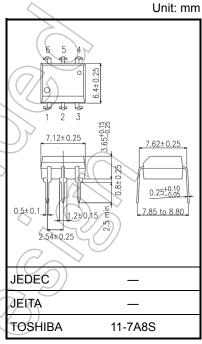
TLP797J

Telecommunication Measurement Instrumenation FA

The TOSHIBA TLP797J consists of an infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).

The TLP797J is a bi-directional switch can replace mechanical relays in many applications.

- 6 pin DIP (DIP6)
- 1-form-A
- Peak off-state voltage: 600 V (min)
- Trigger LED current: 5 mA (max)
- On-state current: 100 mA (max)
- On-state resistance: 35Ω (max)
- Isolation voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE- approved: EN 60747-5-5 (Note 1)



Weight: 0.4 g (typ.)

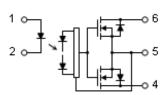
Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

Construction mechanical rating

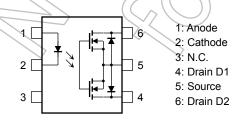
	7.62 mm pitch standard type	10.16 mm pitch TLPXXXF type
Creepage distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation thickness	0.4 mm (min)	0.4 mm (min)

Note: When applying safety standard certification, use the standard part number, e.g., TLP797J.

Schematic



Pin Configurations (top view)



Start of commercial production 2001-07

Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
	Forward current		lF	50	mA
	Forward current dera	ting (Ta ≥ 25°C)	ΔI _F /°C	-0.5	mA/°C
	Peak forward current	(100 μs pulse, 100 pps)	IFP	1	A
LED	Reverse voltage		V _R	5	У
	Diode power dissipat	ion	P_D	50	mW
	Diode power dissipat	ion derating (Ta ≥ 25°C)	ΔP _D /°C	-0.5	mW/°C
	Junction temperature		Tj	125	(\c)
	Off-state output term	inal voltage	Voff	600	V
		A connection		100) /
	On-state current	B connection	Ion	100	mA
On-state current derating		C connection		200	
	A connection	(7/_1.0		
	derating	B connection	ΔION/°C	-1.0	mA/°C
Detector	(Ta ≥ 25°C)	C connection		-2.0	
Detector		A connection	1	430	
	Output power dissipation	B connection	Ro	330	mW
		C connection		504	/\\
	Output power	A connection		-4.3	
	dissipation derating	B connection	ΔP ₀ /°C	-3.3	mW / °C
	(Ta ≥ 25°C)	C connection	Ì	-5.04	
	Junction temperature	unction temperature		125	°C
Storage temperature range			T _{stg}	−55 to 125	°C
Operating temperature range			Topr	-40 to 85	°C
Lead soldering temperature (10 s)			Tsol	260	°C
Isolation vo	oltage (AC, 60 s, R.H.	≤ 60 %) (Note 1)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device: Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

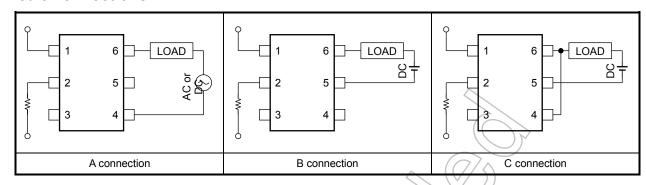
Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{DD}	_	_	480	V
Forward current	lF	7.5	15	25	mA
On-state current	Ion	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

© 2019
Toshiba Electronic Devices & Storage Corporation

2 2019-06-24

Circuit Connections



Individual Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10 mA	1.0	1.15	1.3	٧
LED	Reverse current	IR	V _R = 5 V	-(//	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1 MHz	7	30	_	pF
Detector	Off-state current	loff	V _{OFF} = 600 V			1	μΑ
Detector	Capacitance	Coff	V = 0 V, f = 1 MHz		120	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteris	stics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		l f f (I _{ON} = 100 mA	_	1.6	5	mA
Close LED current		IFC	Ioff = 100 μA	0.1	_	_	mA
Annantian	A connection	$(\bigcirc \bigcirc \bigcirc$	$I_{ON} = 100 \text{ mA}, I_F = 10 \text{ mA}, t < 1 \text{ s}$	_	25	35	
On-state resistance	A connection	Paul	ION = 100 mA, IF = 10 mA	_	30	45	Ω
On-state resistance	B connection	RON	I _{ON} = 100 mA, I _F = 10 mA	_	23	35	22
	C connection		I _{ON} = 200 mA, I _F = 10 mA	-	12	_	

Isolation Characteristics (Ta = 25°C)

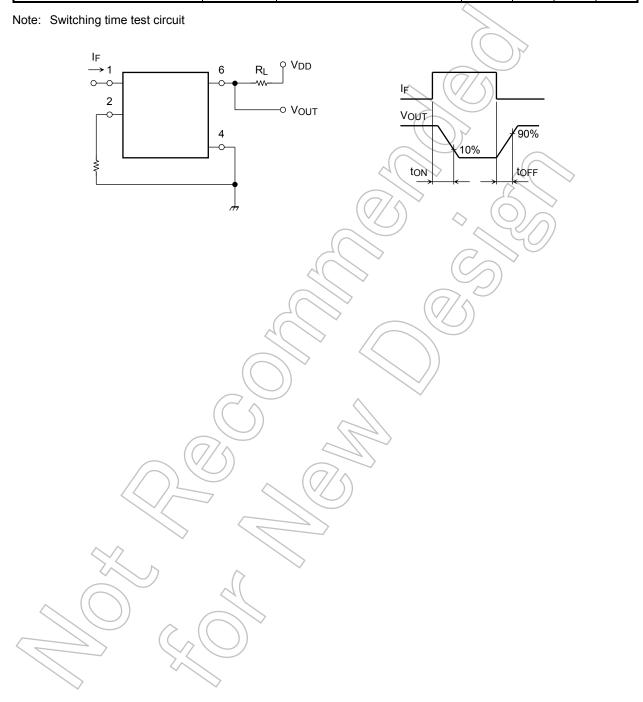
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10^{10}	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	5000	_	_	Vrms

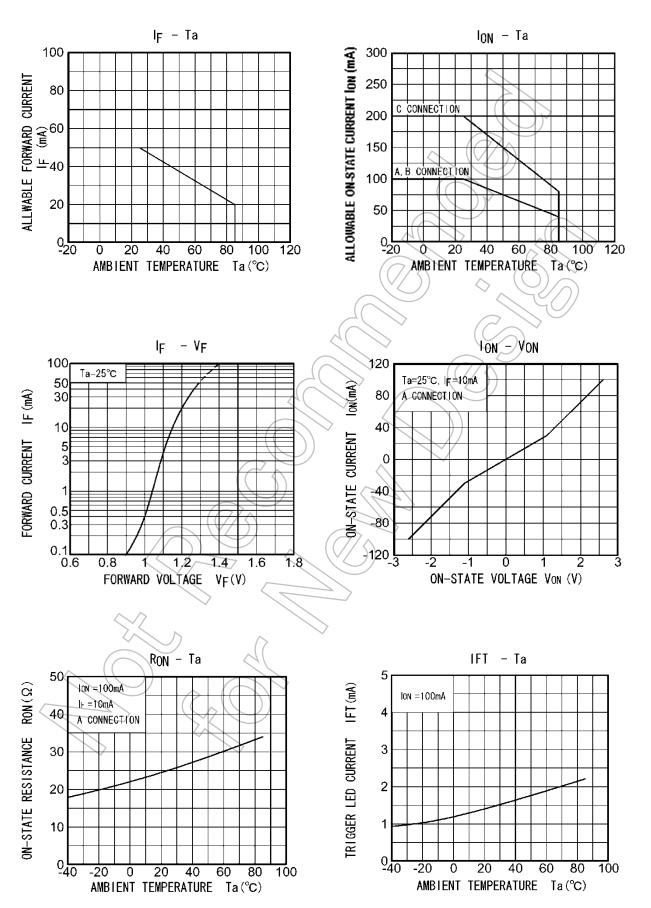
© 2019
Toshiba Electronic Devices & Storage Corporation

3
2019-06-24

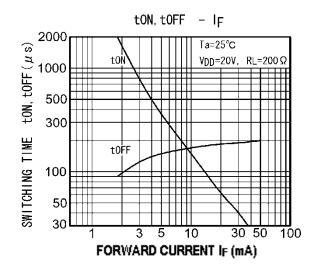
Switching Characteristics (Ta = 25°C)

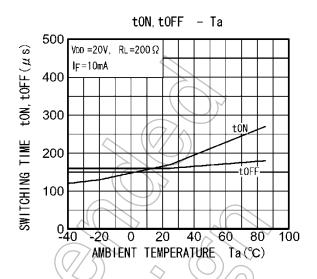
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	ton	$R_L = 200 \Omega$ (Note)	_	0.2	1.5	ms
Turn-off time	toff	V _{DD} = 20 V, I _F = 10 mA	_	0.2	1	ms



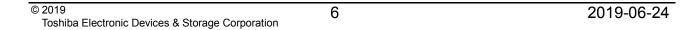


NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical
 equipment, equipment used for automobiles, trains, ships and other transportation, traffic signalling equipment, equipment used to
 control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative or contact us via our website.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
 limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
 technology products (mass destruction weapons). Product and related software and technology may be controlled under the
 applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
 U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
 except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of
 Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled
 substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/